FAIRCHILD SEMICONDUCTOR™

October 1987
Revised January 1999

CD4001BC/CD4011BC
Quad 2-Input NOR Buffered B Series Gate • Quad 2-Input NAND Buffered B Series Gate

General Description

The CD4001BC and CD4011BC quad gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain.

All inputs are protected against static discharge with diodes to V_{DD} and V_{SS}.

Features

- Low power TTL:
  Fan out of 2 driving 74L compatibility: or 1 driving 74LS
- 5V–10V–15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage 1 µA at 15V over full temperature range

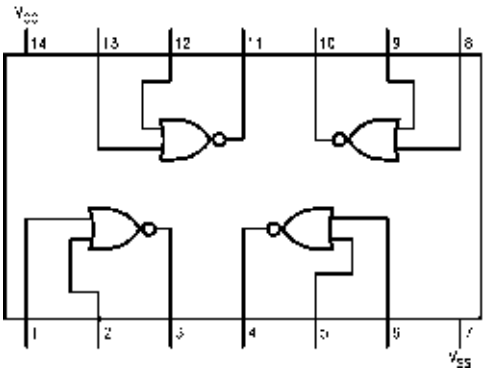
Ordering Code:

Order Number	Package Number	Package Description
CD4001BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
CD4001BCSJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
CD4001BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide
CD4011BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150” Narrow
CD4011BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300” Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter “X” to the ordering code.

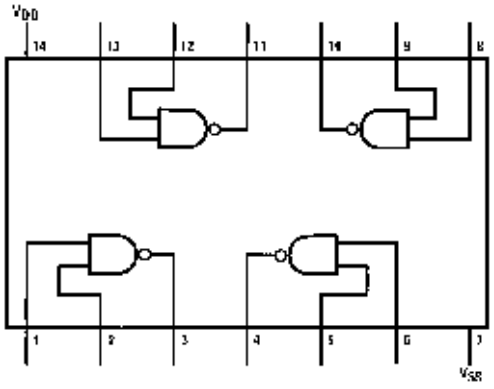
Connection Diagrams

Pin Assignments for DIP, SOIC and SOP
CD4001BC



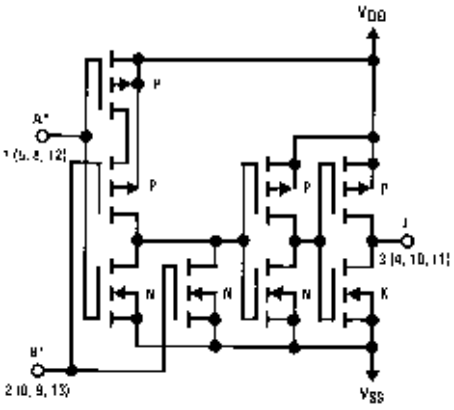
Top View

Pin Assignments for DIP and SOIC
CD4011BC

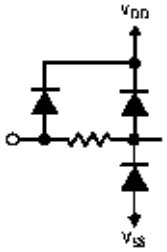


Top View

Schematic Diagrams



CD4001BC



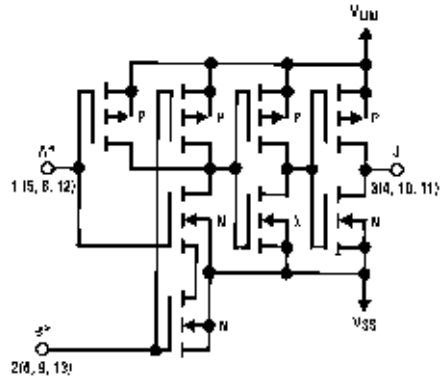
$^1/_4$ of device shown

$J = \overline{A + B}$

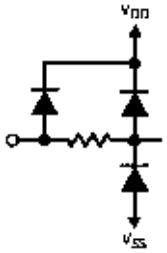
Logical "1" = HIGH

Logical "0" = LOW

All inputs protected by standard CMOS protection circuit.



CD4011BC



$^1/_4$ of device shown

$J = \overline{A \cdot B}$

Logical "1" = HIGH

Logical "0" = LOW

All inputs protected by standard CMOS protection circuit.

Absolute Maximum Ratings(Note 1)

(Note 2)

Voltage at any Pin	−0.5V to V_{DD} +0.5V
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
V_{DD} Range	−0.5 V_{DC} to +18 V_{DC}
Storage Temperature (T_S)	−65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions

Operating Range (V_{DD})	3 V_{DC} to 15 V_{DC}
Operating Temperature Range	
CD4001BC, CD4011BC	−40°C to +85°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions for actual device operation.

Note 2: All voltages measured with respect to V_{SS} unless otherwise specified.

DC Electrical Characteristics (Note 2)

Symbol	Parameter	Conditions	−40°C		+25°C			+85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	V_{DD} = 5V, V_{IN} = V_{DD} or V_{SS}		1		0.004	1		7.5	µA
		V_{DD} = 10V, V_{IN} = V_{DD} or V_{SS}		2		0.005	2		15	µA
		V_{DD} = 15V, V_{IN} = V_{DD} or V_{SS}		4		0.006	4		30	µA
V_{OL}	LOW Level Output Voltage	V_{DD} = 5V		0.05		0	0.05		0.05	V
		V_{DD} = 10V $\lvert I_O \rvert$ < 1 µA		0.05		0	0.05		0.05	V
		V_{DD} = 15V		0.05		0	0.05		0.05	V
V_{OH}	HIGH Level Output Voltage	V_{DD} = 5V	4.95		4.95	5		4.95		V
		V_{DD} = 10V $\lvert I_O \rvert$ < 1 µA	9.95		9.95	10		9.95		V
		V_{DD} = 15V	14.95		14.95	15		14.95		V
V_{IL}	LOW Level Input Voltage	V_{DD} = 5V, V_O = 4.5V		1.5		2	1.5		1.5	V
		V_{DD} = 10V, V_O = 9.0V		3.0		4	3.0		3.0	V
		V_{DD} = 15V, V_O = 13.5V		4.0		6	4.0		4.0	V
V_{IH}	HIGH Level Input Voltage	V_{DD} = 5V, V_O = 0.5V	3.5		3.5	3		3.5		V
		V_{DD} = 10V, V_O = 1.0V	7.0		7.0	6		7.0		V
		V_{DD} = 15V, V_O = 1.5V	11.0		11.0	9		11.0		V
I_{OL}	LOW Level Output Current (Note 3)	V_{DD} = 5V, V_O = 0.4V	0.52		0.44	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.3		1.1	2.25		0.9		mA
		V_{DD} = 15V, V_O = 1.5V	3.6		3.0	8.8		2.4		mA
I_{OH}	HIGH Level Output Current (Note 3)	V_{DD} = 5V, V_O = 4.6V	−0.52		−0.44	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.3		−1.1	−2.25		−0.9		mA
		V_{DD} = 15V, V_O = 13.5V	−3.6		−3.0	−8.8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.30		-10^{-5}	−0.30		−1.0	µA
		V_{DD} = 15V, V_{IN} = 15V		0.30		10^{-5}	0.30		1.0	µA

Note 3: I_{OL} and I_{OH} are tested one output at a time.

AC Electrical Characteristics (Note 4)

CD4001BC: T_A = 25°C, Input t_r; t_f = 20 ns. C_L = 50 pF, R_L = 200k. Typical temperature coefficient is 0.3%/°C.

Symbol	Parameter	Conditions	Typ	Max	Units
t_{PHL}	Propagation Delay Time, HIGH-to-LOW Level	V_{DD} = 5V	120	250	ns
		V_{DD} = 10V	50	100	ns
		V_{DD} = 15V	35	70	ns
t_{PLH}	Propagation Delay Time, LOW-to-HIGH Level	V_{DD} = 5V	110	250	ns
		V_{DD} = 10V	50	100	ns
		V_{DD} = 15V	35	70	ns
t_{THL}, t_{TLH}	Transition Time	V_{DD} = 5V	90	200	ns
		V_{DD} = 10V	50	100	ns
		V_{DD} = 15V	40	80	ns
C_{IN}	Average Input Capacitance	Any Input	5	7.5	pF
C_{PD}	Power Dissipation Capacity	Any Gate	14		pF

Note 4: AC Parameters are guaranteed by DC correlated testing.

AC Electrical Characteristics (Note 5)

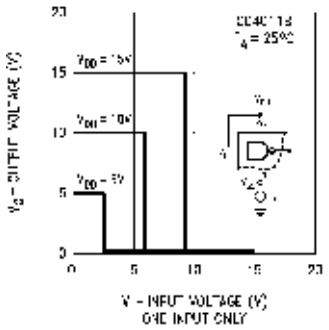
CD4011BC: $T_A = 25°C$, Input t_r; $t_f = 20$ ns. $C_L = 50$ pF, $R_L = 200$k. Typical Temperature Coefficient is 0.3%/°C.

Symbol	Parameter	Conditions	Typ	Max	Units
t_{PHL}	Propagation Delay,	$V_{DD} = 5V$	120	250	ns
	HIGH-to-LOW Level	$V_{DD} = 10V$	50	100	ns
		$V_{DD} = 15V$	35	70	ns
t_{PLH}	Propagation Delay,	$V_{DD} = 5V$	85	250	ns
	LOW-to-HIGH Level	$V_{DD} = 10V$	40	100	ns
		$V_{DD} = 15V$	30	70	ns
t_{THL}, t_{TLH}	Transition Time	$V_{DD} = 5V$	90	200	ns
		$V_{DD} = 10V$	50	100	ns
		$V_{DD} = 15V$	40	80	ns
C_{IN}	Average Input Capacitance	Any Input	5	7.5	pF
C_{PD}	Power Dissipation Capacity	Any Gate	14		pF

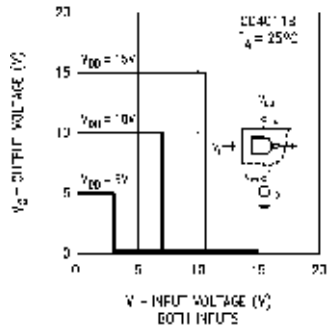
Note 5: AC Parameters are guaranteed by DC correlated testing.

Typical Performance Characteristics

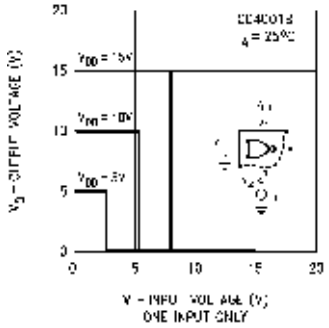
Typical Transfer Characteristics



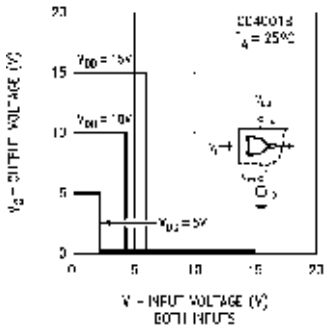
Typical Transfer Characteristics

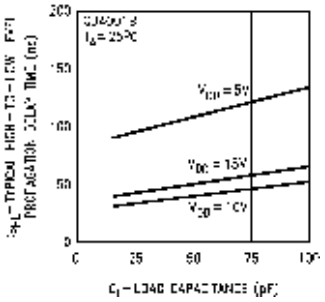


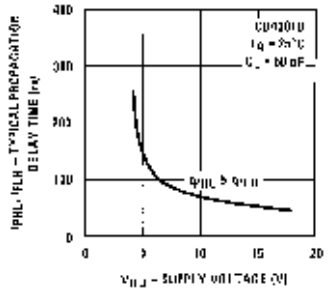
Typical Transfer Characteristics

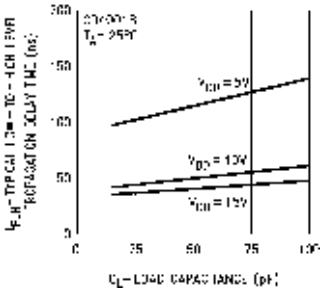


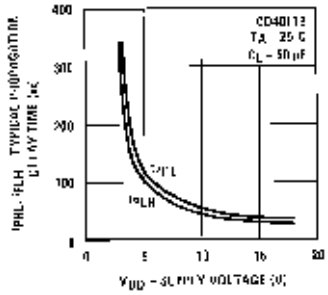
Typical Transfer Characteristics

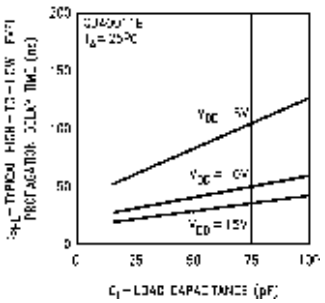


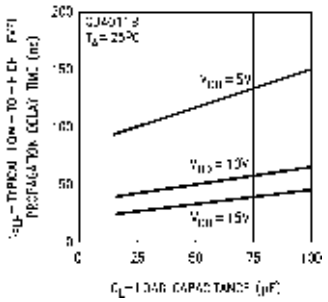


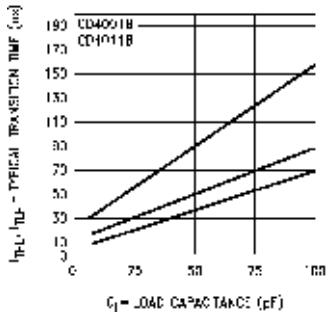


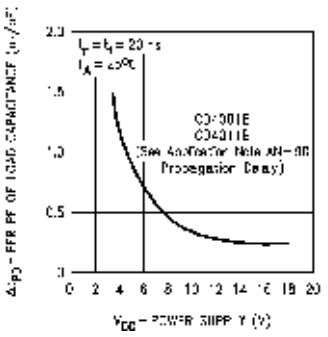


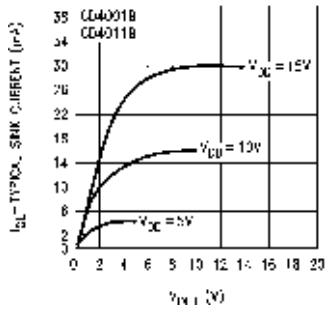


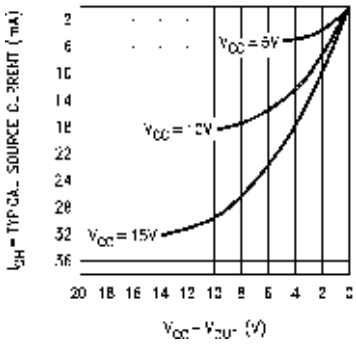



T_A = 25°C
V_{DD} = 5V
V_{DD} = 10V
V_{DD} = 15V
C_L – LOAD CAPACITANCE (pF)

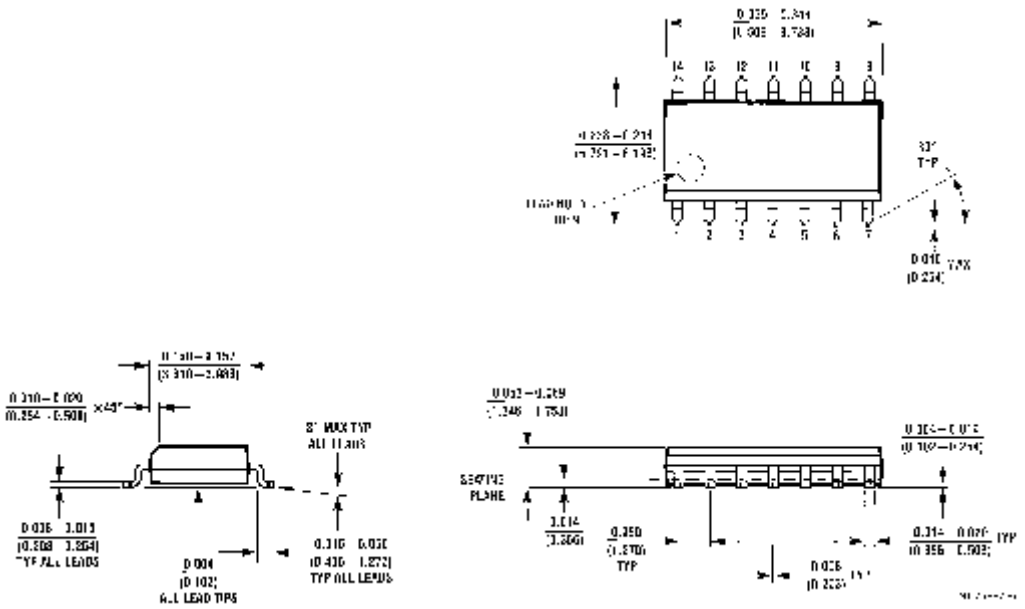

CD4001B
CD4011B
C_L – LOAD CAPACITANCE (pF)


CD4001E
CD4011E
(See Application Note AN-90
Propagation Delay)
V_{DD} – POWER SUPPLY (V)

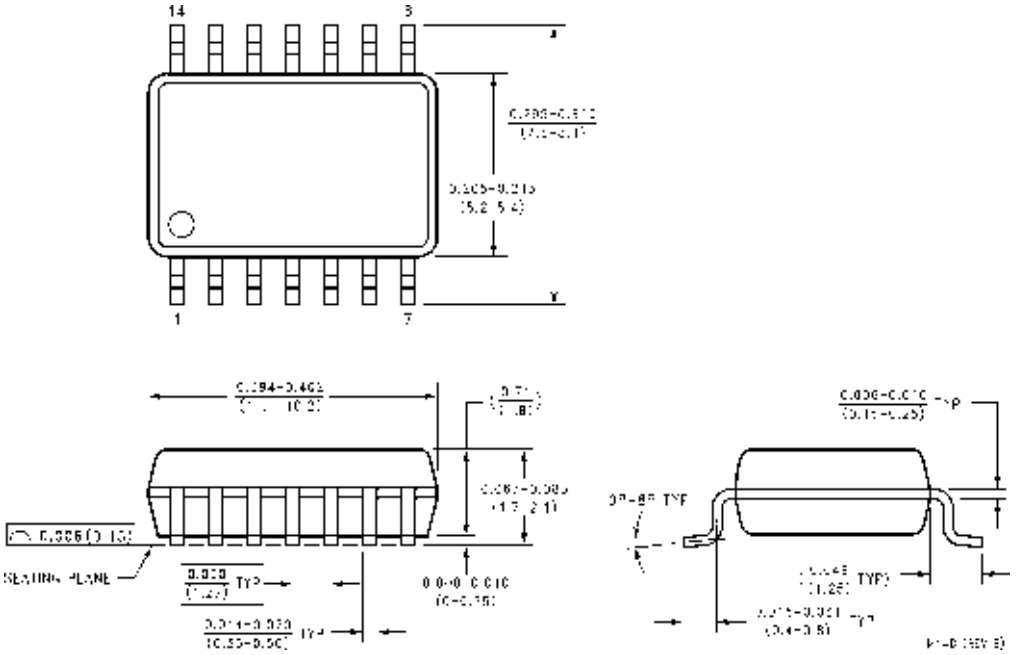

CD4001B
CD4011B
V_{DD} = 15V
V_{DD} = 10V
V_{DD} = 5V


V_{DD} = 5V
V_{DD} = 10V
V_{DD} = 15V
$V_{DD} - V_{OH}$ (V)

Physical Dimensions inches (millimeters) unless otherwise noted

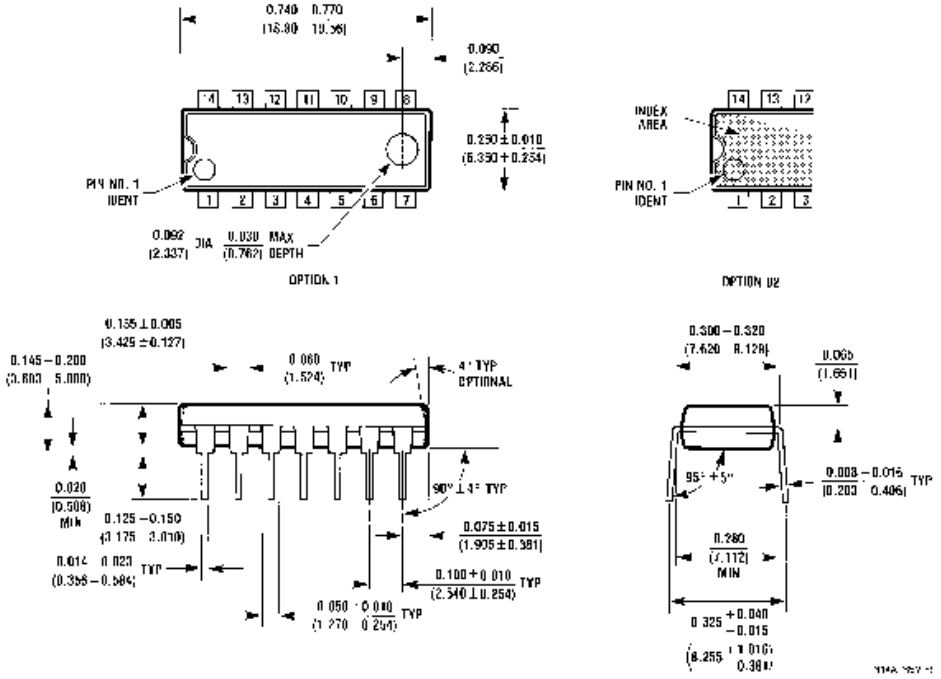


14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N14A